## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1		10/596450	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/11 11:59
L2	2	("6080630").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/11 12:01
L3	. 1	"5466957".PN.	USPAT; USOCR	OR	OFF	2007/10/11 12:00
L4	3	("5466957").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/11 12:01
L5	3	4 and (field or effect or transistor or semiconductor or silicon or source or drain or channel or region or gate or dielectric or dose or concentration or implanting or implantation or body or temperature or higher or ramp-up or extension or LDD or heavy or ion or moderate or amorphousor pocket or surface)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/11 12:05
L6	3	4 and (field or effect or transistor or semiconductor or silicon or source or drain or channel or region or gate or dielectric or dose or concentration or implanting or implantation or body or temperature or higher or ramp-up or extension or LDD or heavy or ion or moderate or amorphousor pocket or surface or first or second or annealing or heating)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/11 12:06
L7	1	"4957824".PN.	USPAT; USOCR	OR	OFF	2007/10/11 12:31
L8	1	"4649629".PN.	USPAT; USOCR	OR	OFF	2007/10/11 12:32